



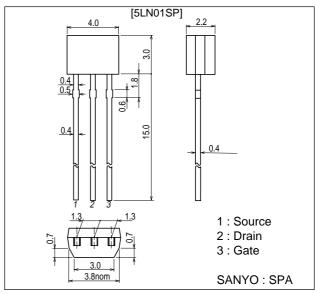
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm 2180



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		50	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		0.1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	0.4	Α
Allowable Power Dissipation	PD		0.25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	50			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =50V, V _{GS} =0			10	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _D S=10V, I _D =100μA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =50mA	0.13	0.18		S

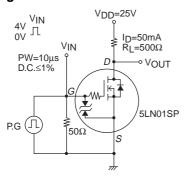
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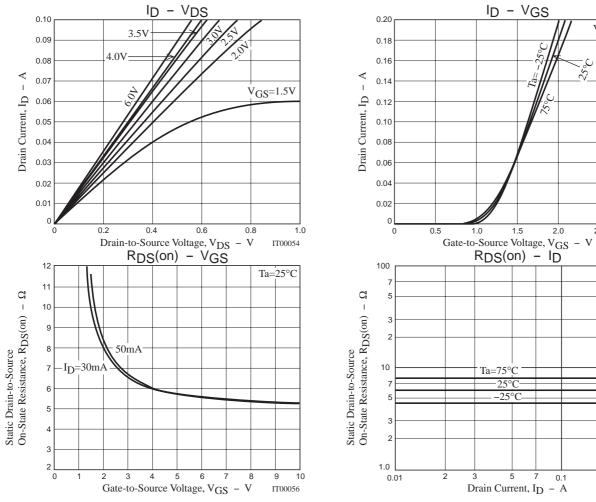
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=50mA, VGS=4V		6	7.8	Ω
	R _{DS} (on)2	ID=30mA, VGS=2.5V		7.1	9.9	Ω
	RDS(on)3	ID=10mA, VGS=1.5V		10	20	Ω
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		6.6		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		4.7		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		1.7		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		18		ns
Rise Time	t _r	See specified Test Circuit		42		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		190		ns
Fall Time	tf	See specified Test Circuit		105		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =100mA		1.57		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =100mA		0.20		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =100mA		0.32		nC
Diode Forward Voltage	VSD	I _S =100mA, V _G S=0		0.85	1.2	V

Switching Time Test Circuit





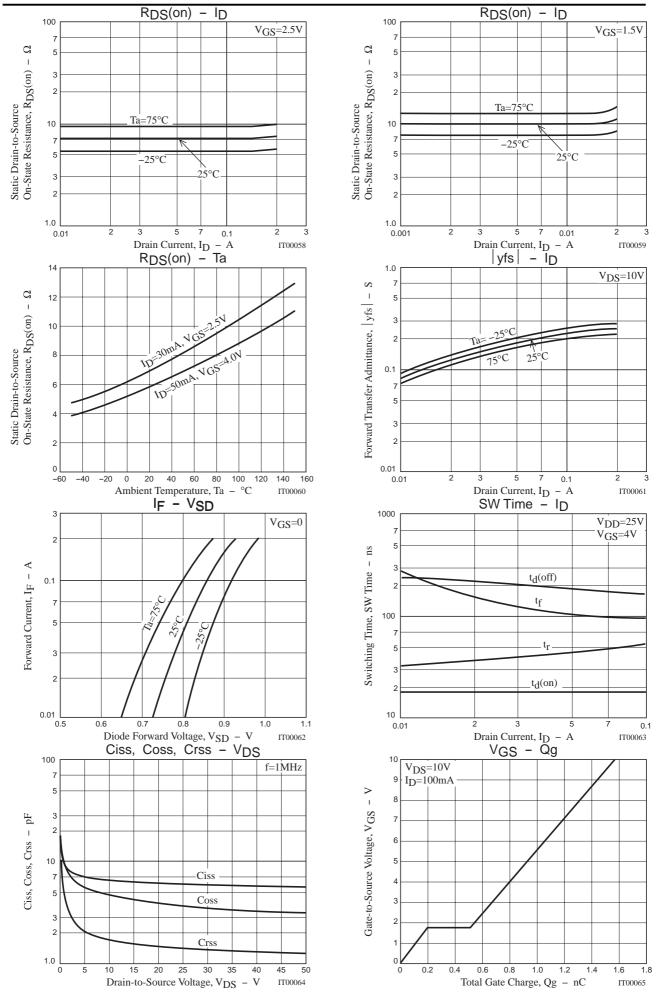
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 $V_{DS}=10V$

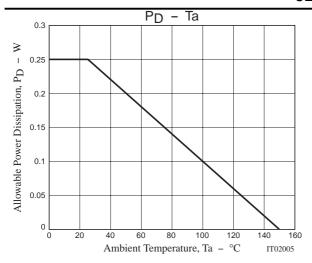
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V_{GS}=4V

5LN01SP



5LN01SP



Note on usage: Since the 5LN01SP is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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